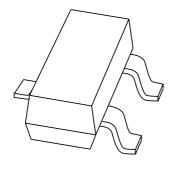
### **DISCRETE SEMICONDUCTORS**

# DATA SHEET



BC846; BC847 NPN general purpose transistors

Product specification Supersedes data of 1997 Mar 12





### **NPN** general purpose transistors

BC846; BC847

#### **FEATURES**

• Low current (max. 100 mA)

• Low voltage (max. 65 V).

#### **APPLICATIONS**

• General purpose switching and amplification.

#### **DESCRIPTION**

NPN transistor in a SOT23 plastic package. PNP complements: BC856 and BC857.

#### **MARKING**

TYPE NUMBER	MARKING CODE	TYPE NUMBER	MARKING CODE <sup>(1)</sup>
BC846	1D*	BC847A	1E*
BC846A	1A*	BC847B	1F*
BC846B	1B*	BC847C	1G*
BC847	1H*		

#### Note

1. \* = p: Made in Hong Kong.

\* = t : Made in Malaysia.

#### **PINNING**

PIN	DESCRIPTION
1	base
2	emitter
3	collector

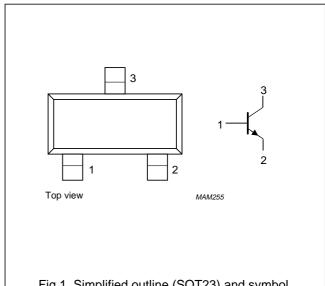


Fig.1 Simplified outline (SOT23) and symbol.

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter			
	BC846		_	80	V
	BC847		_	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base			
	BC846		_	65	V
	BC847		_	45	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	6	V
Ic	collector current (DC)		_	100	mA
I <sub>CM</sub>	peak collector current		_	200	mA
I <sub>BM</sub>	peak base current		_	200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

Philips Semiconductors Product specification

### NPN general purpose transistors

BC846; BC847

#### THERMAL CHARACTERISTICS

SYMBOL	SYMBOL PARAMETER		VALUE	UNIT	
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	500	K/W	

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

#### **CHARACTERISTICS**

 $T_j = 25$  °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	I <sub>E</sub> = 0; V <sub>CB</sub> = 30 V	_	-	15	nA
		I <sub>E</sub> = 0; V <sub>CB</sub> = 30 V; T <sub>j</sub> = 150 °C	_	_	5	μΑ
I <sub>EBO</sub>	emitter cut-off current	I <sub>C</sub> = 0; V <sub>EB</sub> = 5 V	_	_	100	nA
h <sub>FE</sub>	DC current gain	$I_C = 10 \mu A; V_{CE} = 5 V;$				
	BC846A; BC847A	see Figs 2, 3 and 4	_	90	_	
	BC846B; BC847B		_	150	_	
	BC847C		_	270	_	
	DC current gain	I <sub>C</sub> = 2 mA; V <sub>CE</sub> = 5 V;				
	BC846	see Figs 2, 3 and 4	110	_	450	
	BC847		110	_	800	
	BC846A;BC847A		110	180	220	
	BC846B; BC847B		200	290	450	
	BC847C		420	520	800	
$V_{CEsat}$	collector-emitter saturation	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	_	90	250	mV
	voltage	$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}$	_	200	600	mV
$V_{BEsat}$	base-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; \text{ note 1}$	_	700	_	mV
		$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}; \text{ note 1}$	_	900	_	mV
$V_{BE}$	base-emitter voltage	I <sub>C</sub> = 2 mA; V <sub>CE</sub> = 5 V; note 2	580	660	700	mV
		$I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V}; \text{ note 2}$	_	_	770	mV
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0$ ; $V_{CB} = 10 \text{ V}$ ; $f = 1 \text{ MHz}$ ;	_	2.5	_	pF
f <sub>T</sub>	transition frequency	$I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V}; f = 100 \text{ MHz};$	100	_	_	MHz
F	noise figure		_	2	10	dB

#### **Notes**

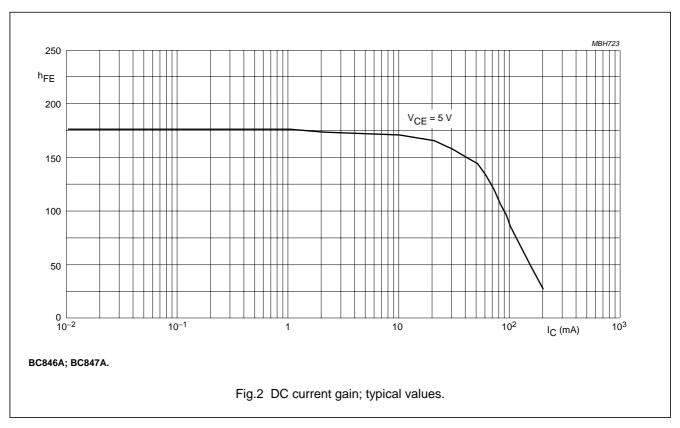
- 1.  $V_{BEsat}$  decreases by about 1.7 mV/K with increasing temperature.
- 2.  $V_{BE}$  decreases by about 2 mV/K with increasing temperature.

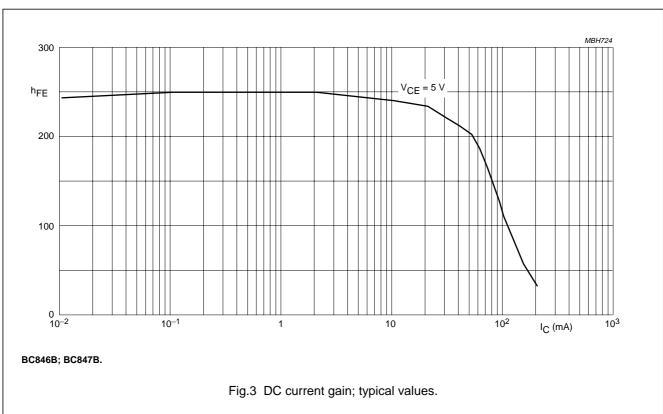
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Philips Semiconductors Product specification

### NPN general purpose transistors

BC846; BC847



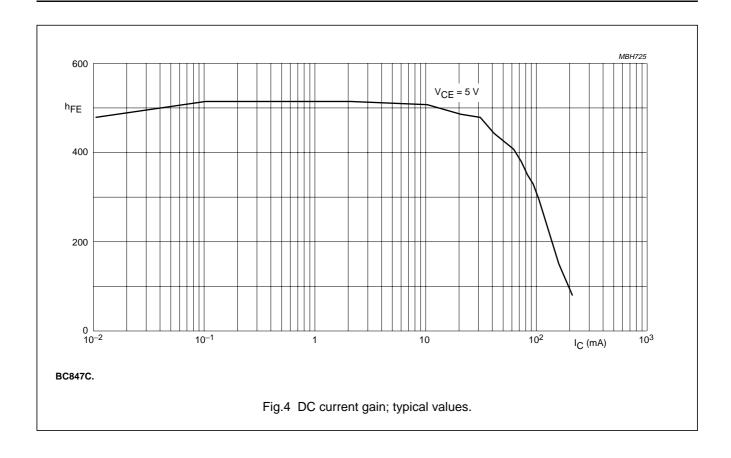


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### NPN general purpose transistors

BC846; BC847



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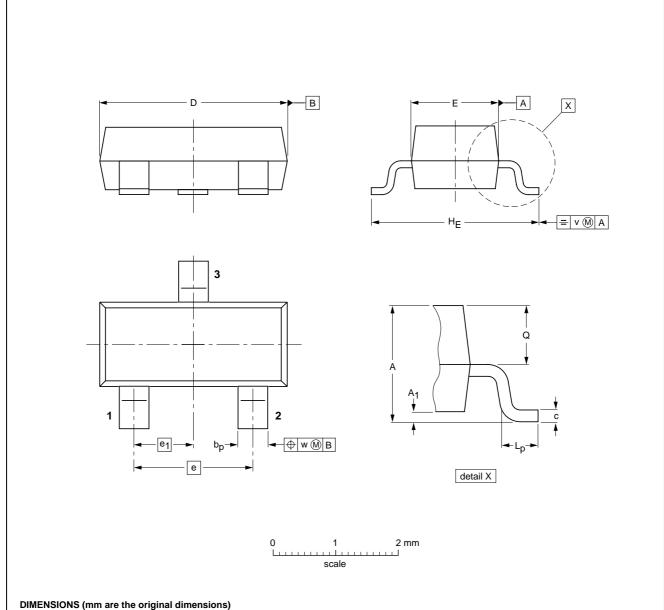
### NPN general purpose transistors

BC846; BC847

#### **PACKAGE OUTLINE**

Plastic surface mounted package; 3 leads

SOT23



UNIT	Α	A <sub>1</sub> max.	bp	С	D	E	е	e <sub>1</sub>	HE	Lp	Q	٧	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE		REFERENCES				ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT23						97-02-28

Product specification Philips Semiconductors

### NPN general purpose transistors

BC846; BC847

#### **DEFINITIONS**

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

#### LIFE SUPPORT APPLICATIONS

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